

### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
V <sub>CBO</sub>	Collector-Base Voltage	40	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous	200	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150 degrees C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

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# **PNP General Purpose Amplifier**

(continued)

Electrical Characteristics TA = 25°C unless otherwise noted						
Symbol	Parameter	Test Conditions	Min	Max	Units	
OFF CHA	RACTERISTICS					
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	40		V	

V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	40		V	
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \ \mu {\rm A}, \ I_{\rm E} = 0$	40		V	
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, \ I_{C} = 0$	5.0		V	
I <sub>BL</sub>	Base Cutoff Current	$V_{CE} = 30 \text{ V}, \text{ V}_{BE} = 3.0 \text{ V}$		50	nA	
I <sub>CEX</sub>	Collector Cutoff Current	$V_{CE} = 30 \text{ V}, \text{ V}_{BE} = 3.0 \text{ V}$		50	nA	

## **ON CHARACTERISTICS**

h <sub>FE</sub>	DC Current Gain *	I <sub>C</sub> = 0.1 mA, V <sub>CE</sub> = 1.0 V	60		
		$I_{\rm C} = 1.0 \text{ mA}, V_{\rm CE} = 1.0 \text{ V}$	80		
		$I_{\rm C} = 10 \text{ mA}, V_{\rm CE} = 1.0 \text{ V}$	100	300	
		$I_{c} = 50 \text{ mA}, V_{ce} = 1.0 \text{ V}$	60		
		$I_{C} = 100 \text{ mA}, V_{CE} = 1.0 \text{ V}$	30		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1.0 \text{ mA}$		0.25	V
. ,	_	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5.0 \text{ mA}$		0.4	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1.0 \text{ mA}$	0.65	0.85	V
		$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5.0 \text{ mA}$		0.95	V

## SMALL SIGNAL CHARACTERISTICS

f <sub>T</sub>	Current Gain - Bandwidth Product	$I_{C} = 10 \text{ mA}, V_{CE} = 20 \text{ V},$ f = 100 MHz	250		MHz
C <sub>obo</sub>	Output Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$ f = 100 kHz		4.5	pF
C <sub>ibo</sub>	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0,$ f = 100 kHz		10.0	pF
NF	Noise Figure (except MMPQ3906)	$I_{C}$ = 100 μA, $V_{CE}$ = 5.0 V, R <sub>S</sub> =1.0kΩ, f=10 Hz to 15.7 kHz		4.0	dB

## SWITCHING CHARACTERISTICS (except MMPQ3906)

t <sub>d</sub>	Delay Time	$V_{CC} = 3.0 \text{ V}, \text{ V}_{BE} = 0.5 \text{ V},$	35	ns
tr	Rise Time	I <sub>C</sub> = 10 mA, I <sub>B1</sub> = 1.0 mA	35	ns
ts	Storage Time	$V_{CC} = 3.0 \text{ V}, \text{ I}_{C} = 10 \text{ mA}$	225	ns
t <sub>f</sub>	Fall Time	$I_{B1} = I_{B2} = 1.0 \text{ mA}$	75	ns

\*Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

## Spice Model

PNP (Is=1.41f Xti=3 Eg=1.11 Vaf=18.7 Bf=180.7 Ne=1.5 Ise=0 Ikf=80m Xtb=1.5 Br=4.977 Nc=2 Isc=0 Ikr=0 Rc=2.5 Cjc=9.728p Mjc=.5776 Vjc=.75 Fc=.5 Cje=8.063p Mje=.3677 Vje=.75 Tr=33.42n Tf=179.3p Itf=.4 Vtf=4 Xtf=6 Rb=10)

## **PNP General Purpose Amplifier**

(continued)

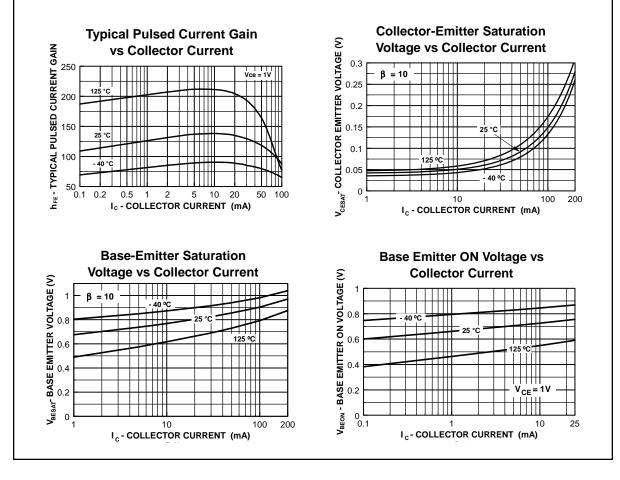
Symbol	Characteristic	N	Max	
		2N3906	*PZT3906	
P <sub>D</sub>	Total Device Dissipation	625	1,000	mW
	Derate above 25°C	5.0	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	125	°C/W

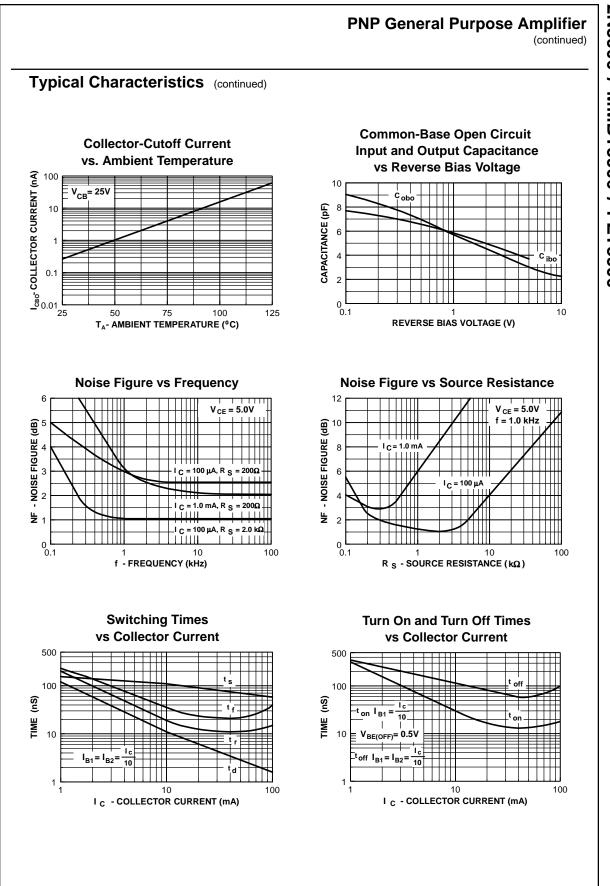
Symbol	Characteristic	Max Units		
		**MMBT3906	MMPQ3906	
P <sub>D</sub>	Total Device Dissipation	350	1,000	mW
	Derate above 25°C	2.8	8.0	mW/∘C
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	357		°C/W
	Effective 4 Die		125	°C/W
	Each Die		240	°C/W

\*Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm<sup>2</sup>.

\*\*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

## **Typical Characteristics**

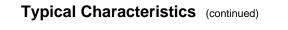


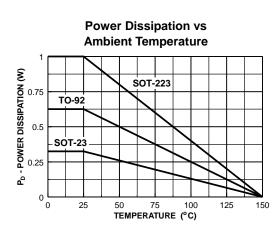


2N3906 / MMBT3906 / PZT3906

# PNP General Purpose Amplifier (continued)







2N3906 / MMBT3906 / PZT3906

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